



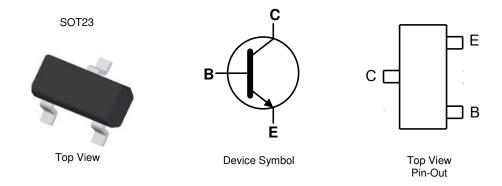
#### 350V NPN HIGH VOLTAGE TRANSISTOR IN SOT23

#### **Features**

- BV<sub>CEO</sub> > 350V
- I<sub>C</sub> = 500mA High Collector Current
- 350mW Power Dissipation
- h<sub>FE</sub> of 15 @ I<sub>C</sub>=100mA
- Complementary Part Number: FMMT6520
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



### **Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT6517TA	AEC-Q101	517	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

### **Marking Information**

517 = Product Type Marking Code



# **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	350	V
Collector-Emitter Voltage	V <sub>CEO</sub>	350	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Base Current	I <sub>B</sub>	25	mA
Collector Current	Ic	500	mA

# Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol Value		Unit	
Power Dissipation	(Note 5)	5	310	mW
rower dissipation	(Note 6)	$P_{D}$	350	IIIVV
Thermal Desistance Junction to Ambient	(Note 5)	5	403	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	357	- C/VV
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	350	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	٧	С

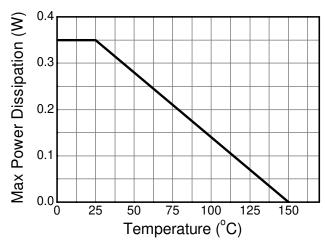
Notes:

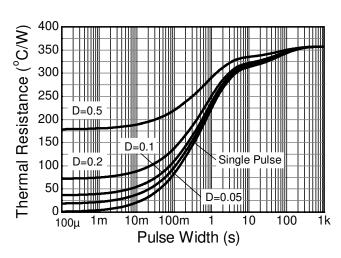
- 5. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in steady state condition.

  6. Same as note (5), except the device is mounted on 15mm x 15mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



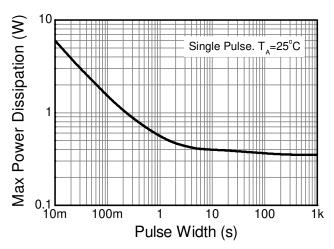
# **Thermal Characteristics and Derating information**





# **Derating Curve**

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



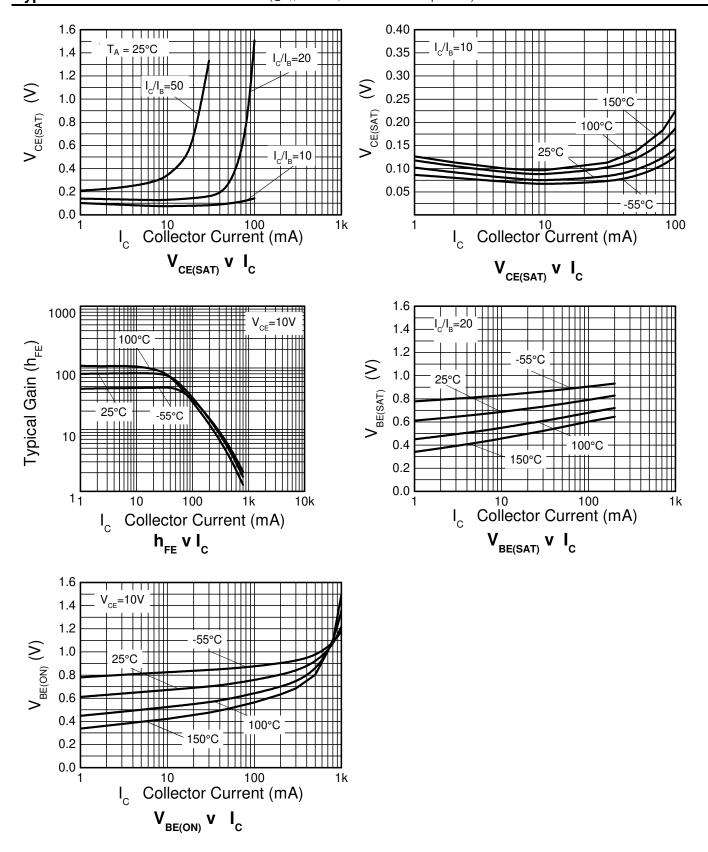
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	350	_	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	350	_	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	_	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	_	50	nA	V <sub>CB</sub> = 250V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	50	nA	V <sub>EB</sub> = 6V
Static Forward Current Transfer Ratio (Note 9)	h <sub>FE</sub>	20 30 30 20 15	_	  200 200 	_	$\begin{split} &I_{C} = 1 mA,  V_{CE} = 10 V \\ &I_{C} = 10 mA,  V_{CE} = 10 V \\ &I_{C} = 30 mA,  V_{CE} = 10 V \\ &I_{C} = 50 mA,  V_{CE} = 10 V \\ &I_{C} = 100 mA,  V_{CE} = 10 V \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(SAT)</sub>	_	_	0.3 0.35 0.5 1.0	V	$I_C$ = 10mA, $I_B$ = 1mA $I_C$ = 20mA, $I_B$ = 2mA $I_C$ = 30mA, $I_B$ = 3mA $I_C$ = 50mA, $I_B$ = 5mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(SAT)</sub>	_	_	0.80 0.85 0.90	V	$I_C$ = 10mA, $I_B$ = 1mA $I_C$ = 20mA, $I_B$ = 2mA $I_C$ = 30mA, $I_B$ = 3mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(ON)</sub>	_	_	2.0	V	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 10V
Output Capacitance	C <sub>OBO</sub>	_	_	6	pF	V <sub>CB</sub> = 20V. f = 1MHz
Transition Frequency	f <sub>T</sub>	50	_	_	MHz	V <sub>CE</sub> = 20V, I <sub>C</sub> = 10mA, f = 20MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

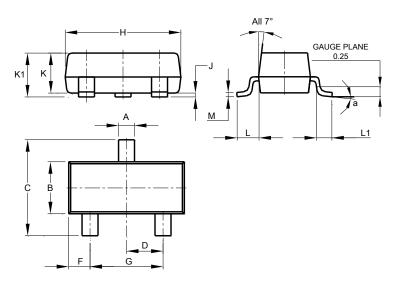




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

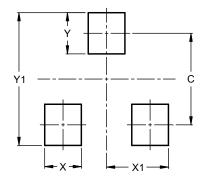


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Υ	0.9			
Y1	29			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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